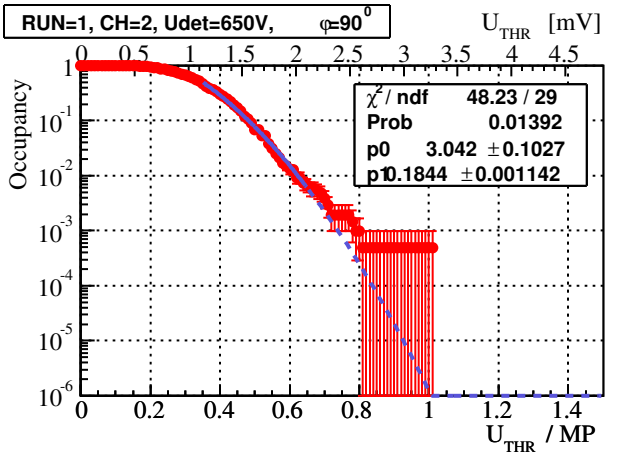
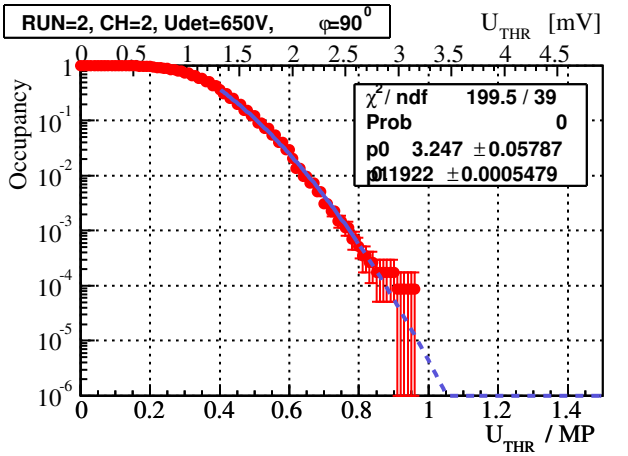
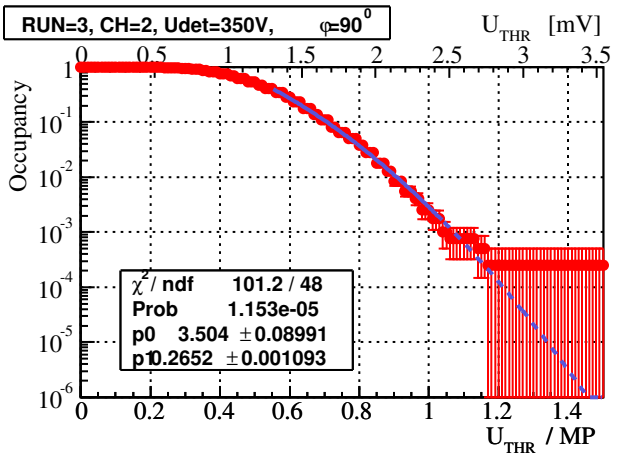
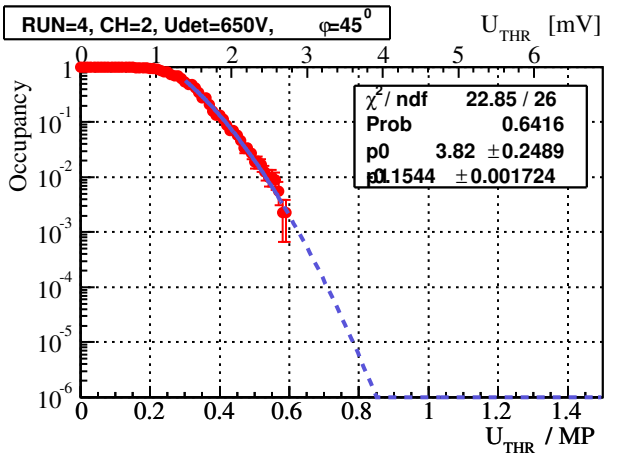
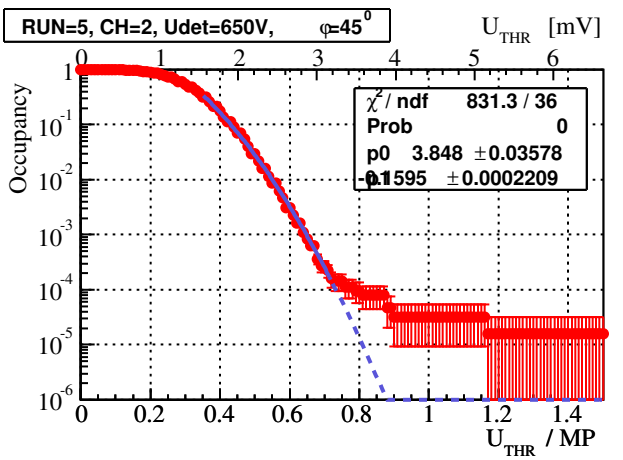
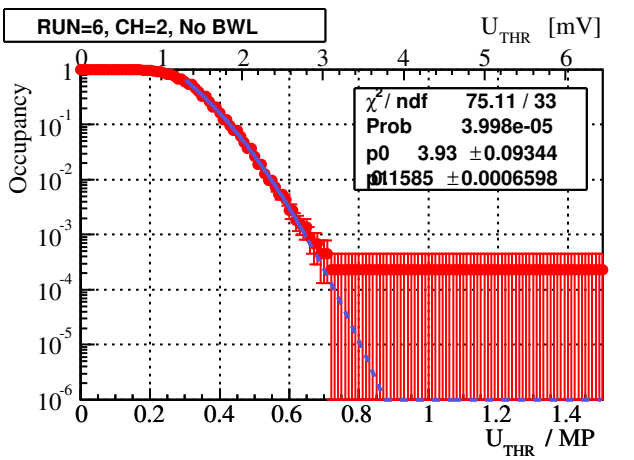

RUN=1, CH=2, Udet=650V, φ=90°
U_THR [mV]
Occupancy
χ² / ndf 48.23 / 29
Prob 0.01392
p0 3.042 ±0.1027
p1 0.1844 ±0.001142
U_THR / MP

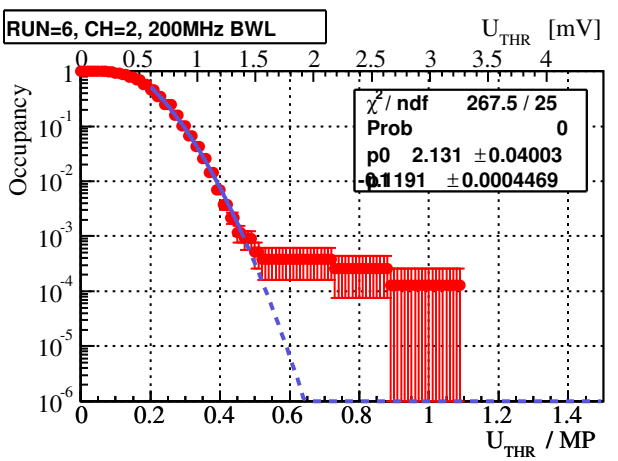

RUN=2, CH=2, Udet=650V, φ=90°
U_THR [mV]
Occupancy
χ² / ndf 199.5 / 39
Prob 0
p0 3.247 ±0.05787
p1 0.1922 ±0.0005479
U_THR / MP


RUN=3, CH=2, Udet=350V, φ=90°
U_THR [mV]
Occupancy
χ² / ndf 101.2 / 48
Prob 1.153e-05
p0 3.504 ±0.08991
p1 0.2652 ±0.001093
U_THR / MP


RUN=4, CH=2, Udet=650V, φ=45°
U_THR [mV]
Occupancy
χ² / ndf 22.85 / 26
Prob 0.6416
p0 3.82 ±0.2489
p1 0.1544 ±0.001724
U_THR / MP


RUN=5, CH=2, Udet=650V, φ=45°
U_THR [mV]
Occupancy
χ² / ndf 831.3 / 36
Prob 0
p0 3.848 ±0.03578
p1 -0.1595 ±0.0002209
U_THR / MP


RUN=6, CH=2, No BWL
U_THR [mV]
Occupancy
χ² / ndf 75.11 / 33
Prob 3.998e-05
p0 3.93 ±0.09344
p1 0.1585 ±0.0006598
U_THR / MP


RUN=6, CH=2, 200MHz BWL
U_THR [mV]
Occupancy
χ² / ndf 267.5 / 25
Prob 0
p0 2.131 ±0.04003
p1 -0.1191 ±0.0004469
U_THR / MP